

PART OSBOLETE - USE DGD05473



**DGD0547** 

HIGH FREQUENCY HIGH-SIDE AND LOW-SIDE GATE DRIVER IN W-DFN3030-10

#### Description

The DGD0547 is a high-frequency gate driver capable of driving Nchannel MOSFETs. The floating high-side driver is rated up to 50V.

The DGD0547 logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with MCUs. UVLO for high-side and low-side will protect a MOSFET with loss of supply. To protect MOSFETs, cross conduction prevention logic prevents the HO and LO outputs from being on at the same time.

Fast and well-matched propagation delays allow a higher switching frequency, enabling a smaller, more compact power switching design, using smaller associated components. To minimize space an internal bootstrap diode is included. The DGD0547 is offered in the W-DFN3030-10 (Type TH) package and operates over an extended -40°C to +125°C temperature range.

#### Applications

#### DC-DC Converters

- Motor Controls
- **Battery Powered Hand Tools**
- eCia Devices
- **Class D Power Amplifiers**

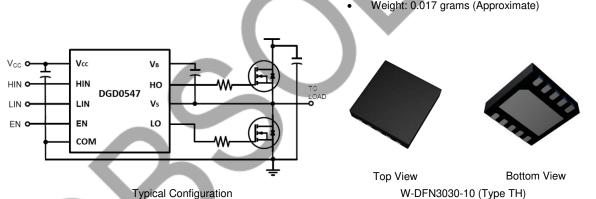
#### Features

- 50V Floating High-Side Driver
- Drives Two N-channel MOSFETs in a Half-Bridge Configuration
- 1.5A Source / 2.5A Sink Output Current Capability
- Internal Bootstrap Diode Included •
- Undervoltage Lockout for High-Side and Low-Side Drivers •
- Delay Matching Maxmimum of 5ns •
- Propagation Delay Typical of 20ns
- Logic Input (HIN, LIN and EN) 3.3V Capability
- Ultra Low Standby Currents (<1µA)
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Case: W-DFN3030-10
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish Matte Tin Finish
- Solderable per MIL-STD-202, Method 208 3
- Weight: 0.017 grams (Approximate)



# Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DGD0547FN-7	DGD0547	7	8	3,000
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.				

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.dlodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



DGD0547 = Product Type Marking Code YY = Year (ex: 21 = 2021) WW = Week (01 to 53)



# **Pin Diagrams**

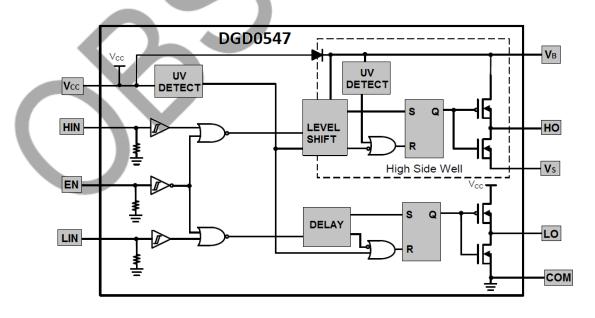
$V_{\rm cc}$			10	LO
NC	2		9	СОМ
VB	3	PAD	8	LIN
НО	4		7	HIN
Vs	5		6	EN

Top View: W-DFN3030-10 (Type TH)

### **Pin Descriptions**

Pin Number	Pin Name	Function
1	Vcc	Low-Side and Logic Supply
2	NC	No Connect (No Internal Connection)
3	VB	High-Side Floating Supply
4	HO	High-Side Gate Drive Output
5	Vs	High-Side Floating Supply Return
6	EN	Logic Input Enable, a Logic Low turns off Gate Driver
7	HIN	Logic Input for High-Side Gate Driver, in Phase with HO
8	LIN	Logic Input for Low-Side Gate Driver, in Phase with LO
9	COM	Low-Side and Logic Return
10	LO	Low-Side Gate Drive Output
PAD	Substrate	Connect to COM on PCB

# Functional Block Diagram





#### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

VB Vs VHO dVs/dt	-0.3 to +60 VB-14 to VB+0.3 Vs-0.3 to VB+0.3 50	V V V
Vно	Vs-0.3 to V <sub>B</sub> +0.3	V
	-	V
dVs / dt	50	
u v 37 ul	50	V/ns
Vcc	-0.3 to +14	V
VLO	-0.3 to Vcc+0.3	V
VIN	-0.3 to Vcc+0.3	V
I <sub>BD</sub>	1	A
	V <sub>CC</sub> V <sub>LO</sub> V <sub>IN</sub>	V <sub>CC</sub> -0.3 to +14   V <sub>LO</sub> -0.3 to V <sub>CC</sub> +0.3   V <sub>IN</sub> -0.3 to V <sub>CC</sub> +0.3

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor (Note 5)	PD	0.4	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	64	°C/W
Thermal Resistance, Junction to Case (Note 5)	Rejc	42	°C/W
Operating Temperature	TJ	+150	
Lead Temperature (Soldering, 10s)	Ī. J	+300	°C
Storage Temperature Range	Tstg	-55 to +150	

Note: 5. When mounted on a standard JEDEC 2-layer FR-4 board.

### **Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
High-Side Floating Supply	VB	V <sub>S</sub> + 5	V <sub>S</sub> + 14	V
High-Side Floating Supply Offset Voltage	Vs	(Note 6)	50 (Note 7)	V
High-Side Floating Output Voltage	Vно	Vs	VB	V
Logic and Low Side Fixed Supply Voltage	V <sub>CC</sub>	5	14	V
Low-Side Output Voltage	VLO	0	Vcc	V
Logic Input Voltage (HIN, LIN and EN)	VIN	0	5	V
Ambient Temperature	TA	-40	+125	°C

Notes: 6. Logic operation for Vs of -5V to +50V.

7. Provided VB doesn't exceed absolute maximum rating of 60V.



Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Logic "1" Input Voltage	VIH	2.4	_	-	V	-
Logic "0" Input Voltage	VIL	-	-	0.8	V	-
Enable Logic "1" Input Voltage	VENIH	1.6	-	-	V	-
Enable Logic "0" Input Voltage	VENIL	-	-	0.7	V	-
Input Voltage Hysteresis	VINHYS	-	0.6	-	V	-
Enable Input Voltage Hysteresis	VENINHYS	-	0.1	-	V	L
High Level Output Voltage, Vыаs - Vo	Vон	-	0.45	0.6	V	I <sub>O+</sub> = 100mA
Low Level Output Voltage, V <sub>O</sub>	V <sub>OL</sub>	-	0.15	0.22	V	I <sub>O-</sub> = 100mA
Offset Supply Leakage Current	Ilk	-	1	5	μA	$V_B = V_S = 60V$
Vcc Shutdown Supply Current	ICCSD	-	0	1	μA	$V_{IN} = 0V \text{ or } 5V, V_{EN} = 0$
Vcc Quiescent Supply Current	lccq	-	130	200	μA	$V_{IN} = 0V \text{ or } 5V$
Vcc Operating Supply Current	ICCOP	-	7.3		mA	fs = 500kHz
VBS Quiescent Supply Current	IBSQ	-	40	100	μA	$V_{IN} = 0V \text{ or } 5V$
VBS Operating Supply Current	IBSOP	-	7.3	-	mA	fs = 500kHz
Logic "1" Input Bias Current	I <sub>IN+</sub>	-		50	μA	$V_{IN} = 5V$
Logic "0" Input Bias Current	I <sub>IN-</sub>	-	-	5	μA	$V_{IN} = 0V$
Enable Logic "1" Input Bias Current	IENIN+	-	43	60	μA	$V_{IN} = 5V$
Enable Logic "0" Input Bias Current	I <sub>ENIN-</sub>	-	0	5	μA	$V_{IN} = 0V$
VBS Supply Undervoltage Positive Going Threshold	VBSUV+	4.1	4.5	4.9	V	-
VBS Supply Undervoltage Negative Going Threshold	VBSUV-	3.6	4.0	4.4	V	-
Vcc Supply Undervoltage Positive Going Threshold	Vccuv+	4.1	4.5	4.9	V	-
Vcc Supply Undervoltage Negative Going Threshold	Vccuv-	3.6	4.0	4.4	V	-
Output High Short Circuit Pulsed Current	I <sub>O+</sub>	1.0	1.5	_	А	V <sub>O</sub> = 0V, PW ≤ 10µs
Output Low Short Circuit Pulsed Current	lo-	1.9	2.5	-	А	Vo = 15V, PW ≤ 10µs
Forward Voltage of Bootstrap Diode	V <sub>F1</sub>		0.67	-	V	I <sub>F</sub> = 100μA
Forward Voltage of Bootstrap Diode	V <sub>F2</sub>	-	1.2	_	V	I <sub>F</sub> = 100mA

DC Electrical Characteristics (V<sub>CC</sub> = V<sub>BS</sub> = 12V, COM = V<sub>S</sub> = 0V, @T<sub>A</sub> = +25°C, unless otherwise specified.) (Note 8)

Note: 8. The VIN and IIN parameters are applicable to the two logic pins: HIN, LIN and EN. The VO and IO parameters are applicable to the respective output pins: HO and LO.

### **AC Electrical Characteristics** (V<sub>CC</sub> = V<sub>BS</sub> = 12V, COM = V<sub>S</sub> = 0V, C<sub>L</sub> = 1000pF, @T<sub>A</sub> = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Turn-On Propagation Delay	ton	-	20	35	ns	—
Turn-Off Propagation Delay	toff	-	23	56	ns	Vs = 50V
Delay Matching, HO & LO Turn-On	t <sub>DM</sub>	-	-	5	ns	-
Turn-On Rise Time	tR	-	16	30	ns	-
Turn-Off Fall Time	tF	_	12	25	ns	-



### **Timing Waveforms**

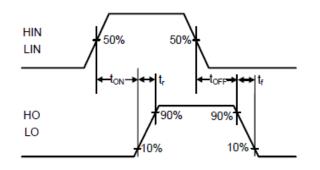
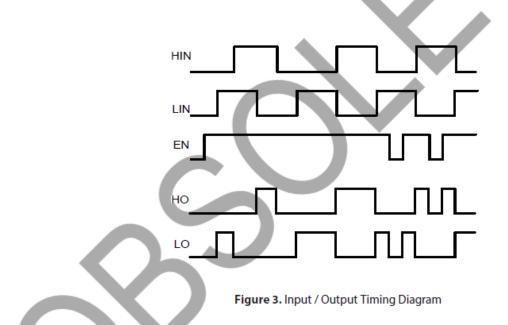


Figure 1. Switching Time Waveform Definitions

HIN LIN 50% 50% LO HO tom on + + tom off 90% LO HO

Figure 2. Delay Matching Waveform Definitions





#### Typical Performance Characteristics (@TA = +25°C, unless otherwise specified.)

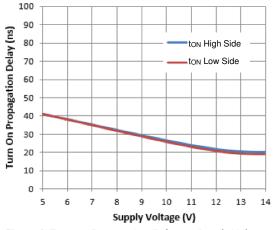


Figure 4. Turn-on Propagation Delay vs. Supply Voltage

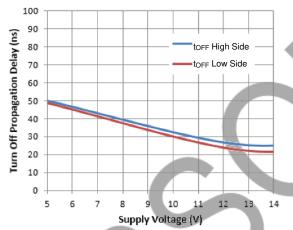


Figure 6. Turn-off Propagation Delay vs. Supply Voltage

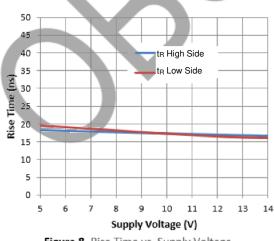


Figure 8. Rise Time vs. Supply Voltage

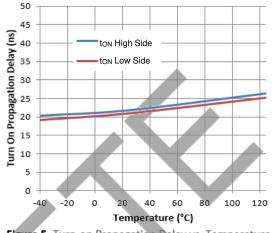


Figure 5. Turn-on Propagation Delay vs. Temperature

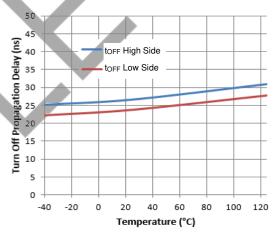


Figure 7. Turn-off Propagation Delay vs. Temperature

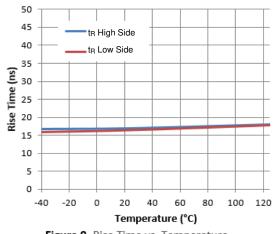
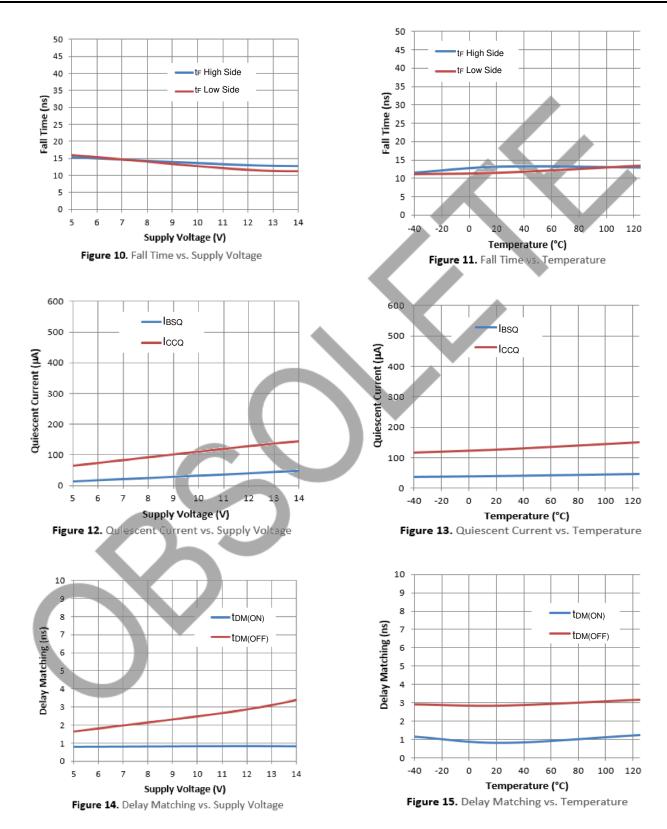


Figure 9. Rise Time vs. Temperature

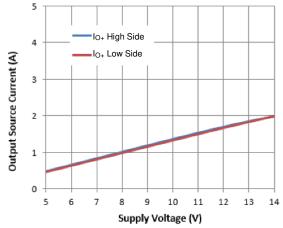


# Typical Performance Characteristics (continued)





#### Typical Performance Characteristics (continued)



#### Figure 16. Output Source Current vs. Supply Voltage

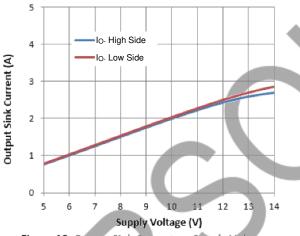


Figure 18. Output Sink Current vs. Supply Voltage

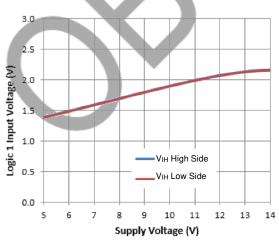
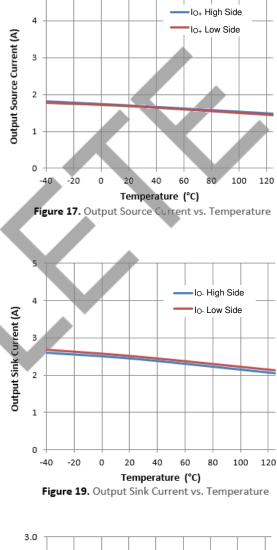


Figure 20. Logic 1 Input Voltage vs. Supply Voltage



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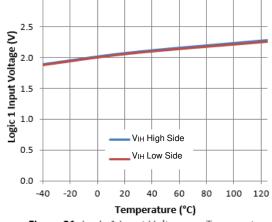


Figure 21. Logic 1 Input Voltage vs. Temperature



# Typical Performance Characteristics (continued)

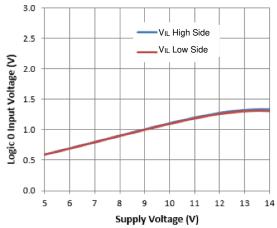
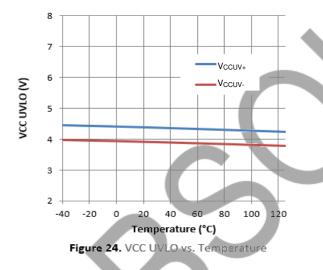


Figure 22. Logic 0 Input Voltage vs. Supply Voltage



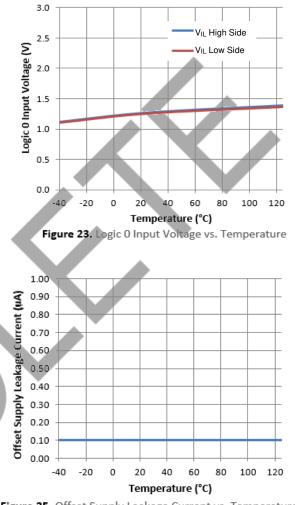
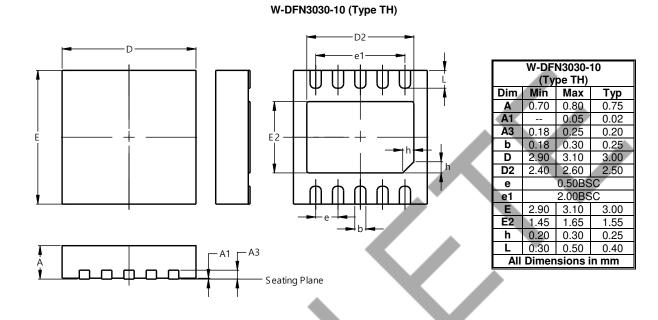


Figure 25. Offset Supply Leakage Current vs. Temperature



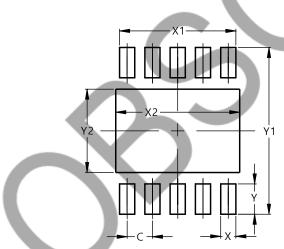
### Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.500
X	0.300
X1	2.300
X2	2.600
Y	0.600
Y1	3.300
Y2	1.650

# W-DFN3030-10 (Type TH)



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